

General Description

The MAX8510/MAX8511/MAX8512 ultra-low-noise, lowdropout (LDO) linear regulators are designed to deliver up to 120mA continuous output current. These regulators achieve a low 120mV dropout for 120mA load current. The MAX8510 uses an advanced architecture to achieve ultra-low output voltage noise of 11µVRMS and PSRR of 54dB at 100kHz.

The MAX8511 does not require a bypass capacitor, hence achieving the smallest PC board area. The MAX8512's output voltage can be adjusted with an external divider.

The MAX8510/MAX8511 are preset to a variety of voltages in the 1.5V to 4.5V range. Designed with a P-channel MOSFET series pass transistor, the MAX8510/MAX8511/ MAX8512 maintain very low ground current (40µA).

The regulators are designed and optimized to work with low-value, low-cost ceramic capacitors. The MAX8510 requires only 1µF (typ) of output capacitance for stability with any load. When disabled, current consumption drops to below 1µA.

Package options include a 5-pin SC70 and a tiny 2mm x 2mm x 0.8mm TDFN package.

Applications

Cellular and Cordless Phones

PDA and Palmtop Computers

Base Stations

Bluetooth Portable Radios and Accessories

Wireless I ANs

Digital Cameras

Personal Stereos

Portable and Battery-Powered Equipment

Features

- ♦ Space-Saving SC70 and TDFN (2mm x 2mm) Packages
- 11µV_{RMS} Output Noise at 100Hz to 100kHz Bandwidth (MAX8510)
- ♦ 78dB PSRR at 1kHz (MAX8510)
- ♦ 120mV Dropout at 120mA Load
- ♦ Stable with 1µF Ceramic Capacitor for Any Load
- ♦ Guaranteed 120mA Output
- Only Need Input and Output Capacitors (MAX8511)
- Output Voltages: 1.5V, 1.8V, 2.5V, 2.6V, 2.7V, 2.8V, 2.85V, 3V, 3.3V, 4.5V (MAX8510/MAX8511) and Adjustable (MAX8512)
- ♦ Low 40µA Ground Current
- ♦ Excellent Load/Line Transient
- **Overcurrent and Thermal Protection**

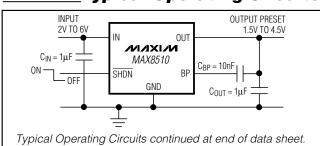
Ordering Information

PART*	TEMP RANGE	PIN-PACKAGE		
MAX8510EXKxy-T	-40°C to +85°C	5 SC70-5		
d. 1 11 1 1 1		17.6		

*xy is the output voltage code (see Output Voltage Selector Guide). Other versions between 1.5V and 4.5V are available in 100mV increments. Contact factory for other versions.

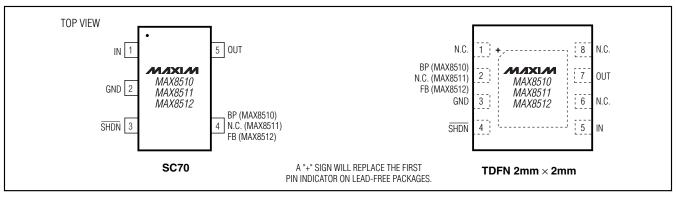
Ordering Information continued at end of data sheet.

Typical Operating Circuits



Output Voltage Selector Guide appears at end of data sheet.

Pin Configuration



MIXIM

Maxim Integrated Products 1

ABSOLUTE MAXIMUM RATINGS

IN to GND	0.3V to +7V
Output Short-Circuit Duration	Infinite
OUT, SHDN to GND	-0.3V to (IN + 0.3V)
FB, BP, N.C. to GND0.	.3V to (OUT + 0.3V)
Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
5-Pin SC70 (derate 3.1mW/°C above +70°	°C)0.247W
8-Pin TDFN (derate 61.9mW/°C above = 7	'0°C)0.953W

hetaJA	
5-Pin SC70	324°C/W
8-Pin TDFN	83.9°C/W
Operating Temperature Range	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{IN} = V_{OUT} + 0.5V, T_A = -40^{\circ}C$ to $+85^{\circ}C$, unless otherwise noted. $C_{IN} = 1\mu F, C_{OUT} = 1\mu F, C_{BP} = 10nF$. Typical values are at $+25^{\circ}C$; the MAX8512 is tested with 2.45V output, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Input Voltage Range	V _{IN}			2		6	V
		I _{OUT} = 1mA, T _A = +25°C		-1		+1	%
Output Voltage Accuracy		$I_{OUT} = 100\mu A$ to 80mA, T_A	-2		+2		
		$I_{OUT} = 100\mu A \text{ to } 80\text{mA}$	-3		+3		
Maximum Output Current	lout			120			mA
Current Limit	ILIM	OUT = 90% of nominal val	ue	130	200	300	mA
		V _{OUT} ≥ 3V, I _{OUT} = 80mA			80	170	
		V _{OUT} ≥ 3V, I _{OUT} = 120mA			120		
Drangust Valtage (Nata 0)		2.5V ≤ V _{OUT} < 3V, l _{OUT} = 8	80mA		90	200	\/
Dropout Voltage (Note 2)		2.5V ≤ V _{OUT} < 3V, I _{OUT} = 120mA 2V ≤ V _{OUT} < 2.5V, I _{OUT} = 80mA			135		mV
					120	250	
		$2V \le V_{OUT} < 2.5V$, $I_{OUT} = 120$ mA			180		
Ground Current	lo	I _{OUT} = 0.05mA			40	90	
Ground Current	lQ	V _{IN} = V _{OUT} (nom) - 0.1V, I _{OUT} = 0mA			220	500	μΑ
Line Regulation	V _{LNR}	$V_{IN} = (V_{OUT} + 0.5V)$ to 6V, $I_{OUT} = 0.1$ mA			0.001		%/V
Load Regulation	V _{LDR}	I _{OUT} = 1mA to 80mA			0.003		%/mA
Chutdown Cupply Current	ISHDN	SHDN = 0V	T _A = +25°C		0.003	1	μА
Shutdown Supply Current			$T_A = +85^{\circ}C$		0.05		
		f 1111= 1 10mm	MAX8510		78		- dB
Ripple Rejection		$f = 1kHz$, $I_{OUT} = 10mA$	MAX8511/MAX8512		72		
	PSRR	f = 10kHz, I _{OUT} = 10mA	MAX8510		75		
			MAX8511/MAX8512		65		
		f 100kl = 1 10A	MAX8510		54		
		$f = 100kHz$, $I_{OUT} = 10mA$	MAX8511/ MAX8512		46		

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ELECTRICAL CHARACTERISTICS (continued)

 $(V_{IN} = V_{OUT} + 0.5V, T_A = -40^{\circ}C$ to +85°C, unless otherwise noted. $C_{IN} = 1\mu F, C_{OUT} = 1\mu F, C_{BP} = 10nF$. Typical values are at +25°C; the MAX8512 is tested with 2.45V output, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CON	MIN	TYP	MAX	UNITS		
TATAMETER	011111111111111111111111111111111111111		MAX8510	10001		III/A/X	Oitiio	
		f = 100Hz to $100kHz$,			11		μV	
Output Noise Voltage		$I_{LOAD} = 10mA$	MAX8511/MAX8512		230			
(RMS)		f = 100Hz to 100kHz, I _{LOAD} = 80mA	MAX8510		13			
			MAX8511/MAX8512		230			
Shutdown Exit Delay		$R_{LOAD} = 50\Omega$ (Note3)				300	μs	
SHDN Logic Low Level		$V_{IN} = 2V \text{ to } 6V$				0.4	V	
SHDN Logic High Level		V _{IN} = 2V to 6V		1.5			V	
CUDN Is and Disa Ormand		$V_{IN} = 6V$, $\overline{SHDN} = 0V$ or	$T_A = +25^{\circ}C$					
SHDN Input Bias Current		6V	$T_A = +85^{\circ}C$		0.01		† µA	
FB Input Bias Current		V 0VV 40V	T _A = +25°C		0.006	0.1		
(MAX8512)		$V_{IN} = 6V, V_{FB} = 1.3V$	$T_A = +85^{\circ}C$		0.01		μA	
Thermal Shutdown			•		160		°C	
Thermal-Shutdown Hysteresis					10		°C	

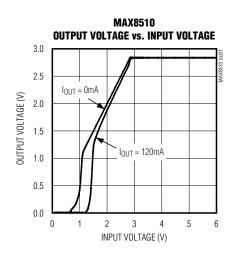
Note 1: Limits are 100% tested at +25°C. Limits over operating temperature range are guaranteed by design.

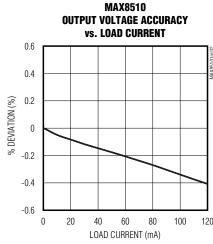
Note 2: Dropout is defined as V_{IN} - V_{OUT} when V_{OUT} is 100mV below the value of V_{OUT} for $V_{IN} = V_{OUT} + 0.5V$.

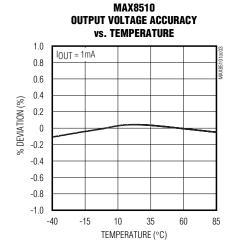
Note 3: Time needed for VouT to reach 90% of final value.

_Typical Operating Characteristics

 $(V_{IN} = V_{OUT} + 0.5V, C_{IN} = 1\mu F, C_{OUT} = 1\mu F, C_{BP} = 10nF, T_{A} = +25^{\circ}C, unless otherwise noted.)$

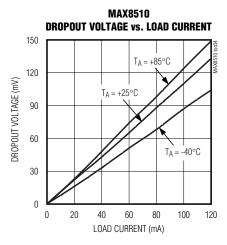


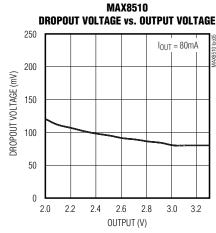


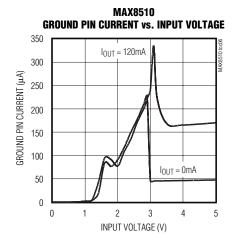


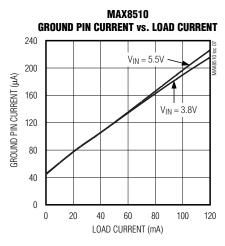
Typical Operating Characteristics (continued)

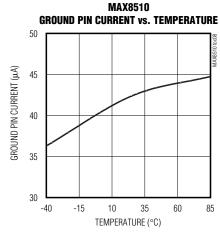
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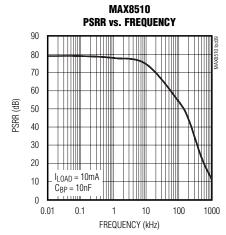


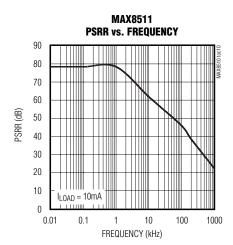


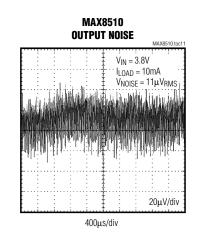


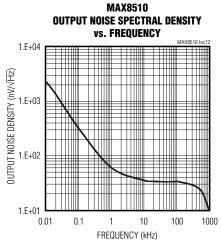






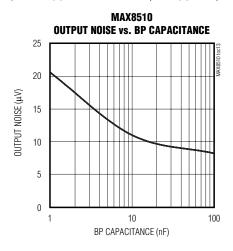


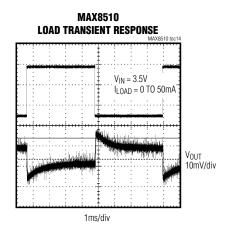


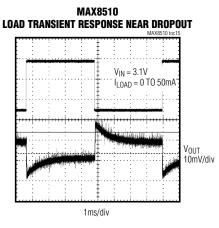


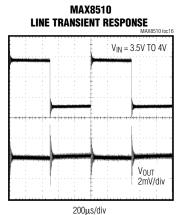
Typical Operating Characteristics (continued)

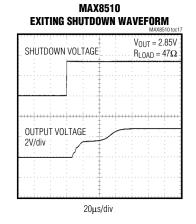
 $(V_{IN} = V_{OUT} + 0.5V, C_{IN} = 1\mu F, C_{OUT} = 1\mu F, C_{BP} = 10nF, T_A = +25^{\circ}C, unless otherwise noted.)$

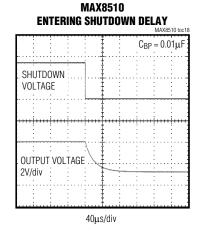


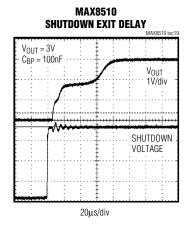


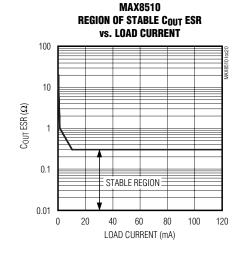












Pin Description

PIN								
MAX	8510	MA	X8511	MAX	8512	NAME	FUNCTION	
SC70	TDFN	SC70	TDFN	SC70	TDFN			
1	5	1	5	1	5	IN	Unregulated Input Supply	
2	3	2	3	2	3	GND	Ground	
3	4	3	4	3	4	SHDN	Shutdown. Pull low to disable the regulator.	
4	2	_	_	_	_	BP	Noise Bypass for Low-Noise Operation. Connect a 10nF capacitor from BP to OUT. It is short to OUT in shutdown mode.	
_	_	_	ı	4	2	FB	Adjustable Output Feedback Point	
5	7	5	7	5	7	OUT	Regulated Output Voltage. Bypass with a capacitor to GND. See the Capacitor Selection and Regulator Stability section for more details.	
_	1, 6, 8	4	1, 2, 6, 8	_	1, 6, 8	N.C.	Not Internally Connected	

Detailed Description

The MAX8510/MAX8511/MAX8512 are ultra-low-noise, low-dropout, low-quiescent current linear regulators designed for space-restricted applications. The parts are available with preset output voltages ranging from 1.5V to 4.5V in 100mV increments. These devices can supply loads up to 120mA. As shown in the *Functional Diagram*, the MAX8510/MAX8511 consist of an innovative bandgap core and noise bypass circuit, error amplifier, P-channel pass transistor, and internal feedback voltage-divider. The MAX8512 allows for adjustable output with an external feedback network.

The 1.225V bandgap reference is connected to the error amplifier's inverting input. The error amplifier compares this reference with the feedback voltage and amplifies the difference. If the feedback voltage is lower than the reference voltage, the pass-transistor gate is pulled low. This allows more current to pass to the output and increases the output voltage. If the feedback voltage is too high, the pass transistor gate is pulled high, allowing less current to pass to the output. The output voltage is fed back through an internal resistor voltage-divider connected to the OUT pin.

An external bypass capacitor connected to BP (MAX8510) reduces noise at the output. Additional blocks include a current limiter, thermal sensor, and shutdown logic.

Internal P-Channel Pass Transistor

The MAX8510/MAX8511/MAX8512 feature a 1Ω (typ) P-channel MOSFET pass transistor. This provides several advantages over similar designs using a PNP pass transistor, including longer battery life. The P-channel MOSFET requires no base drive, which considerably reduces quiescent current. PNP-based regulators waste

considerable current in dropout when the pass transistor saturates. They also use high base-drive current under heavy loads. The MAX8510/MAX8511/MAX8512 do not suffer from these problems and consume only 40µA of quiescent current in light load and 220µA in dropout (see the *Typical Operating Characteristics*).

Output Voltage Selection

The MAX8510/MAX8511 are supplied with factory-set output voltages from 1.5V to 4.5V, in 100mV increments (see *Ordering Information*). The MAX8512 features a user-adjustable output through an external feedback network (see the *Typical Operating Circuits*).

To set the output of the MAX8512, use the following equation:

$$R1 = R2 X \left(\frac{V_{OUT}}{V_{REF}} - 1 \right)$$

where R2 is chosen to be less than 240k Ω and VREF = 1.225V. Use 1% or better resistors.

Shutdown

The MAX8510/MAX8511/MAX8512 feature a low-power shutdown mode that reduces quiescent current less than 1µA. Driving SHDN low disables the voltage reference, error amplifier, gate-drive circuitry, and pass transistor (see the *Functional Diagram*), and the device output enters a high-impedance state. Connect SHDN to IN for normal operation.

Current Limit

The MAX8510/MAX8511/MAX8512 include a current limiter, which monitors and controls the pass transistor's gate voltage, limiting the output current to 200mA. For design purposes, consider the current limit to be

130mA (min) to 300mA (max). The output can be shorted to ground for an indefinite amount of time without damaging the part.

Thermal-Overload Protection

Thermal-overload protection limits total power dissipation in the MAX8510/MAX8511/MAX8512. When the junction temperature exceeds $T_J = +160^{\circ}\text{C}$, the thermal sensor signals the shutdown logic, turning off the pass transistor and allowing the IC to cool down. The thermal sensor turns the pass transistor on again after the IC's junction temperature drops by 10°C, resulting in a pulsed output during continuous thermal-overload conditions.

Thermal-overload protection is designed to protect the MAX8510/MAX8511/MAX8512 in the event of a fault condition. For continual operation, do not exceed the absolute maximum junction temperature rating of $T_J = +150^{\circ}C$.

Operating Region and Power Dissipation

The MAX8510/MAX8511/MAX8512 maximum power dissipation depends on the thermal resistance of the case and circuit board, the temperature difference between the die junction and ambient, and the rate of airflow. The power dissipation across the device is:

The maximum power dissipation is:

$$P_{MAX} = (T_J - T_A) / (\theta_{JC} + \theta_{CA})$$

where T_J - T_A is the temperature difference between the MAX8510/MAX8511/MAX8512 die junction and the surrounding air, θ_{JC} is the thermal resistance of the package, and θ_{CA} is the thermal resistance through the PC board, copper traces, and other materials to the surrounding air.

The GND pin of the MAX8510/MAX8511/MAX8512 performs the dual function of providing an electrical connection to ground and channeling heat away. Connect the GND pin to ground using a large pad or ground plane.

Noise Reduction

For the MAX8510, an external $0.01\mu F$ bypass capacitor between BP and OUT with innovative noise bypass scheme reduces output noises dramatically, exhibiting $11\mu V_{RMS}$ of output voltage noise with $C_{BP}=0.01\mu F$ and $C_{OUT}=1\mu F$. Startup time is minimized by a power-on circuit that precharges the bypass capacitor.

_Applications Information

Capacitor Selection and Regulator Stability

Use a 1µF capacitor on the MĀX8510/MAX8511/MAX8512 input and a 1µF capacitor on the output. Larger input capacitor values and lower ESRs provide better noise rejection and line-transient response. Reduce output noise and improve load-transient response, stability, and power-supply rejection by using large output capacitors. Note that some ceramic dielectrics exhibit large capacitance and ESR variation with temperature. With dielectrics such as Z5U and Y5V, it may be necessary to use a 2.2µF or larger output capacitor to ensure stability at temperatures below -10°C. With X7R or X5R dielectrics, 1µF is sufficient at all operating temperatures. A graph of the region of stable COUT ESR vs. load current is shown in the *Typical Operating Characteristics*.

Use a $0.01\mu F$ bypass capacitor at BP (MAX8510) for low-output voltage noise. The leakage current going into the BP pin should be less than 10nA. Increasing the capacitance slightly decreases the output noise. Values above $0.1\mu F$ and below $0.001\mu F$ are not recommended.

Noise, PSRR, and Transient Response

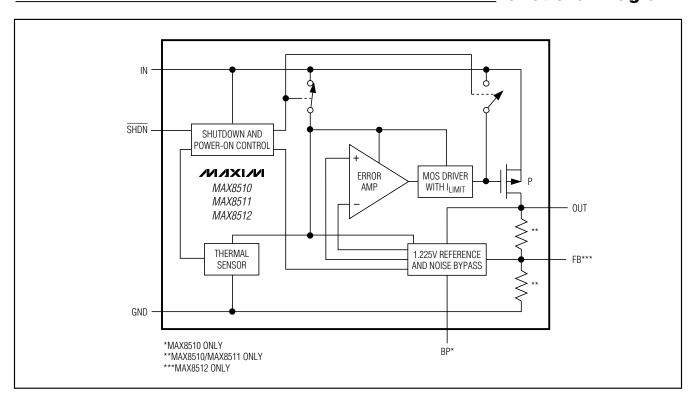
The MAX8510/MAX8511/MAX8512 are designed to deliver ultra-low noise and high PSRR, as well as low dropout and low quiescent currents in battery-powered systems. The MAX8510 power-supply rejection is 78dB at 1kHz and 54dB at 100kHz. The MAX8511/MAX8512 PSRR is 72dB at 1kHz and 46dB at 100kHz (see the Power-Supply Rejection Ratio vs. Frequency graph in the *Typical Operating Characteristics*).

When operating from sources other than batteries, improved supply-noise rejection and transient response can be achieved by increasing the values of the input and output bypass capacitors, and through passive filtering techniques. The *Typical Operating Characteristics* show the MAX8510/MAX8511/MAX8512 line- and load-transient responses.

Dropout Voltage

A regulator's minimum dropout voltage determines the lowest usable supply voltage. In battery-powered systems, this determines the useful end-of-life battery voltage. Because the MAX8510/MAX8511/MAX8512 use a P-channel MOSFET pass transistor, their dropout voltage is a function of drain-to-source on-resistance (RDS(ON)) multiplied by the load current (see the *Typical Operating Characteristics*).

Functional Diagram



Ordering Information (continued)

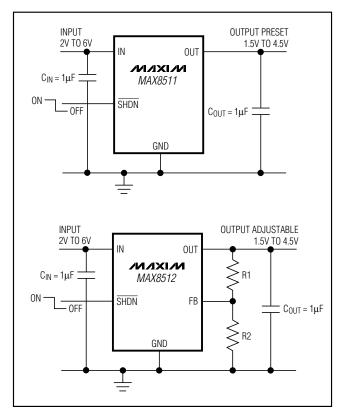
PART*	TEMP RANGE	PIN-PACKAGE
MAX8510EXKxy+T	-40°C to +85°C	5 SC70-5
MAX8510ETAxy+T	-40°C to +85°C	8 Thin DFN-EP** 2mm x 2mm
MAX8511EXKxy-T	-40°C to +85°C	5 SC70-5
MAX8511EXKxy+T	-40°C to +85°C	5 SC70-5
MAX8511ETAxy+T	-40°C to +85°C	8 Thin DFN-EP** 2mm x 2mm
MAX8512EXK-T	-40°C to +85°C	5 SC70-5
MAX8512EXK+T	-40°C to +85°C	5 SC70-5
MAX8512ETA+T	-40°C to +85°C	8 Thin DFN-EP** 2mm x 2mm

^{*}xy is the output voltage code (see Output Voltage Selector Guide). Other versions between 1.5V and 4.5V are available in 100mV increments. Contact factory for other versions.

EP** = Exposed pad.

+Denotes lead-free package.

Typical Operating Circuits (continued)



_Output Voltage Selector Guide

PART	V _{OUT} (V)	TOP MARK
MAX8510EXK16-T	1.6	AEX
MAX8510EXK18-T	1.8	AEA
MAX8510EXK25-T	0.5	AEB
MAX8510ETA25+T	2.5	AAO
MAX8510EXK27-T	2.7	AEC
MAX8510EXK28-T	0.0	AED
MAX8510ETA28+T	2.8	AAR
MAX8510EXK29-T	2.85	ADS
MAX8510EXK30-T	3	ADT
MAX8510ETA30+T	3	AAS
MAX8510EXK33-T	0.0	AEE
MAX8510ETA33+T	3.3	AAT
MAX8510EXK45-T	4.5	AGC
MAX8510ETA45+T	4.5	AAU
MAX8511EXK15-T	1.5	ADU
MAX8511EXK18-T	1.8	AEF
MAX8511ETA18+T	1.8	AAV
MAX8511EXK25-T	2.5	ADV
MAX8511ETA25+T	2.5	AAP
MAX8511EXK26-T	0.0	AEG
MAX8511ETA26+T	2.6	AAW
MAX8511EXK28-T	2.8	AFA
MAX8511EXK29-T	0.05	AFQ
MAX8511ETA29+T	2.85	AAX
MAX8511EXK89-T	2.9	AEH
MAX8511EXK31-T	3.1	ARS
MAX8511EXK33-T	0.0	AEI
MAX8511ETA33+T	3.3	AAY
MAX8511EXK45-T	4.5	AEJ
MAX8512EXK-T	A diu stable	ADW
MAX8512ETA+T	- Adjustable	AAQ

(**Note:** Standard output voltage options, shown in **bold**, are available. Contact the factory for other output voltages between 1.5V and 4.5V. Minimum order quantity is 15,000 units.)

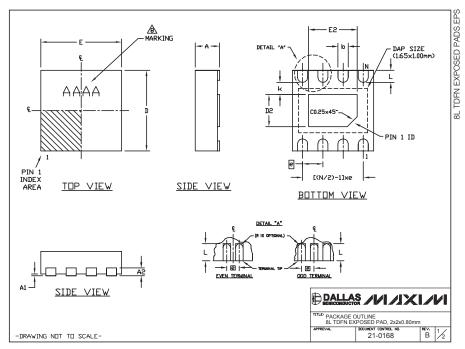
Chip Information

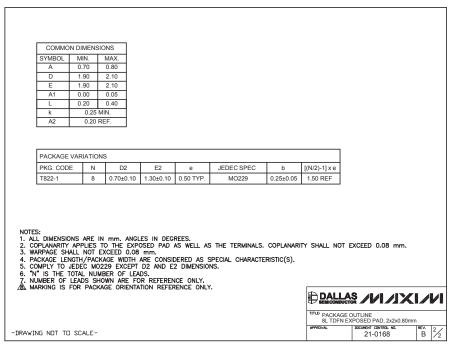
TRANSISTOR COUNT: 284

PROCESS: BiCMOS

Package Information

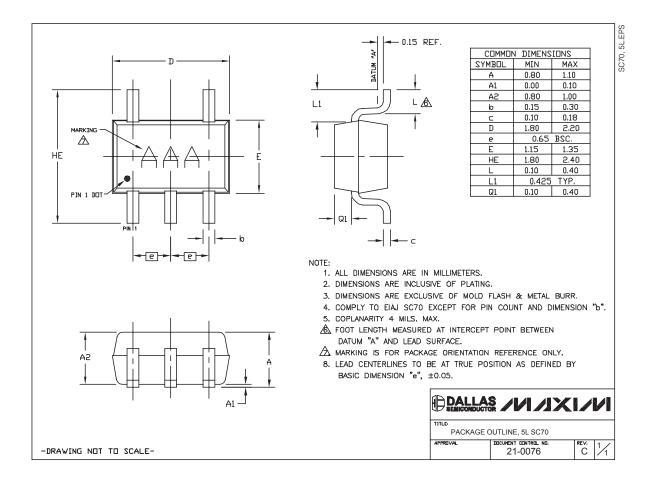
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)





Package Information (continued)

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